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| *Поз.*  *обозначение* | | | Наименование | | | | *Кол.* | | | *Примеч.* | | | |
|  | | | *Диоды* | | | |  | | |  | | | |
| *VD2, VD3* | | | *15SQ045 (Dongguan YFW, Китай)* | | | | *2* | | |  | | | |
| *VD1* | | | *1N4002 (Diotec Semiconductor, Германия)* | | | | *1* | | |  | | | |
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|  | | | *Конденсаторы* | | | |  | | |  | | | |
| *С4* | | | *К10-17Б 1000пФ 50В ±5% (Murata Electronics, Япония)* | | | | *1* | | |  | | | |
| *С1* | | | *К10-17Б 220пФ 50В ±5% (Murata Electronics, Япония)* | | | | *1* | | |  | | | |
| *С7* | | | *К73-17 0,68мкФ 250В ±5%* | | | | *1* | | |  | | | |
|  | | | *(Кузнецкий завод конденсаторов, Россия)* | | | |  | | |  | | | |
| *С6, С8* | | | *К50-35 2200мкФ 35В ±20% (JB Capacitors, Гонконг)* | | | | *2* | | |  | | | |
| *С2, С5* | | | *К50-35 мини 47мкФ 50В ±20% (JB Capacitors, Гонконг)* | | | | *2* | | |  | | | |
| *С3* | | | *К50-35 100мкФ 63В ±20% (JB Capacitors, Гонконг)* | | | |  | | |  | | | |
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|  | | | *Разъёмы* | | | |  | | |  | | | |
| *XS1* | | | *Гнездо стерео 3,5мм ST-025* | | | | *1* | | |  | | | |
|  | | | *(Dragon City Industries, Китай)* | | | |  | | |  | | | |
| *XP1* | | | *Клеммник разъёмный 15EDGRC-3.81-03P (Degson, Китай)* | | | | *1* | | |  | | | |
| *XP2* | | | *Клеммник разъёмный 15EDGRC-3.81-02P (Degson, Китай)* | | | | *1* | | |  | | | |
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|  | | | *Резисторы* | | | |  | | |  | | | |
| *R14, R15* | | | *CF-25 0,25Вт 4.7кОм ±5%* | | | | *2* | | |  | | | |
| *R3, R5* | | | *CF-25 0,25Вт 680Ом ±5%* | | | | *2* | | |  | | | |
| *R12, R13* | | | *CF-25 0,25Вт 3кОм ±5%* | | | | *2* | | |  | | | |
| *R11* | | | *CF-25 0,25Вт 15кОм ±5%* | | | | *1* | | |  | | | |
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| *Поз.*  *обозначение* | | | Наименование | | | | *Кол.* | *Примеч.* | |
| *R7* | | | *CF-25 0,25Вт 1,2кОм ±5%* | | | | *1* |  | |
| *R14* | | | *CF-25 0,25Вт 2кОм ±5%* | | | | *1* |  | |
| *R18* | | | *CF-100 1Вт 10Ом ±5%* | | | | *1* |  | |
| *R4* | | | *CF-100 1Вт 15кОм ±5%* | | | | *2* |  | |
| *R6, R17* | | | *SQP 5Вт 0,1Ом ±5%* | | | | *2* |  | |
| *RP1* | | | *3296W-1-1-2LF 0,25Вт 1кОм ±20% (Bourns, США)* | | | | *1* |  | |
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|  | | | *Транзисторы* | | | |  |  | |
| *VT3, VT4, VT6* | | | *BC546B (Diotec Semiconductor, Германия)* | | | | *3* |  | |
| *VT1, VT2, VT5* | | | *BC556B (Diotec Semiconductor, Германия)* | | | | *3* |  | |
| *VT7* | | | *IRF540NPBF (Infineon Technologies, Германия)* | | | | *1* |  | |
| *VT8* | | | *IRF9540NPBF (Infineon Technologies, Германия)* | | | | *1* |  | |
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